

# XC2173

## Series



ICs for use with Crystal Oscillators (PLL built - in)

### ◆CMOS

### ◆Oscillation Frequency

: 10MHz ~ 25MHz

### ◆Output Frequency : 80MHz ~ 160MHz (5.0V)

: 50MHz ~ 125MHz (3.3V)

### ◆Divider Circuit & PLL Circuit Built-In

### ◆3-State Output

### ◆Oscillation Capacitor & Oscillation Feedback Resistor Built-In

### ◆Mini Mold SOT-26 Package

## ■General Description

The XC2173 series are high frequency, low power consumption CMOS ICs with built-in crystal oscillator, divider and clock multiplier PLL circuits. Output is selectable from any one of the following values for  $f_0$  :  $f_0 \times 5$ ,  $f_0 \times 6$ ,  $f_0 \times 7$ ,  $f_0 \times 8$ ,  $f_0/2$ ,  $f_0/4$ ,  $f_0/8$ . With an oscillation capacitor & oscillation feedback resistor built-in, a stable oscillator circuit can be put together using only an external crystal oscillator. By connecting an external standard clock, the above mentioned output frequencies can be achieved.

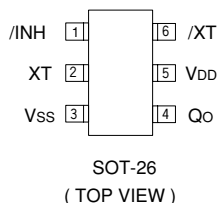
## ■Applications

- Crystal Oscillation Modules
- Computer, DSP Clocks
- Communication Equipment
- Various System Clocks

## ■Features

- Oscillation Frequency** : 10MHz ~ 25MHz
- Divider Ratio** :  $f_0/2$ ,  $f_0/4$ ,  $f_0/8$
- Multiplier** :  $f_0 \times 5$ ,  $f_0 \times 6$ ,  $f_0 \times 7$ ,  $f_0 \times 8$
- Output** : 3-State
- Operating Voltage Range** : 3.3V  $\pm 10\%$  and 5.0V  $\pm 10\%$
- Small Consumption Current** : Stand-by function included\*  
\* oscillation continues in stand-by
- Ultra Small Package** : SOT-26 mini mold

## ■Pin Configuration



## ■Pin Assignment

| PIN NUMBER | PIN NAME | FUNCTION  |
|------------|----------|---|
| 1          | /INH     | Stand-by control*   |
| 2          | XT       | Crystal Oscillator Connection (Input)                         |
| 3          | VSS      | GND   |
| 4          | Qo       | Clock Output  |
| 5          | VDD      | Power Supply  |
| 6          | /XT      | Crystal Oscillator Connection (Output) / Standard Clock Input |

\* Stand-by control pin has pull-up resistor built-in.

## ■INH - B, QO Pin Function

| /INH | Qo                        |
|------|---------------------------|
| "H"  | Divider/Multiplier Output |
| "L"  | High Impedance (Stand-by) |
| OPEN | Divider/Multiplier Output |

"H" = High Level  
"L" = Low Level

## Product Classification

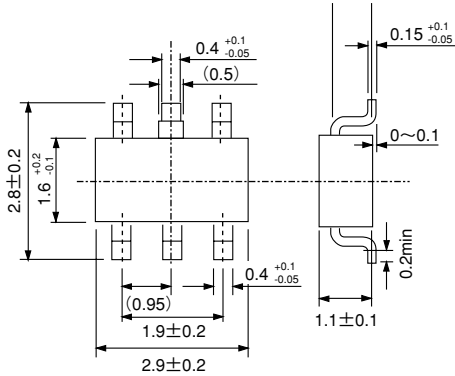
### Ordering Information

XC2173 ①②③④⑤⑥  
 ↑↑↑↑↑↑  
 a b c d e f

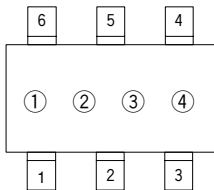
| DESIGNATOR | DESCRIPTION  | DESIGNATOR | DESCRIPTION   |
|------------|--|------------|---|
| a          | Duty Level :<br>C : CMOS (V <sub>DD</sub> /2)  | d          | Input Oscillation Frequency Range<br>1 : 10MHz to 25MHz   |
| b          | Output Capacity :<br>M : Multiplier Output<br>D : Divider Output   | e          | Package :<br>M = SOT-26   |
| c          | Multiplier Ratio or Divider Ratio<br>2 : f <sub>0</sub> / 2                  6 : f <sub>0</sub> x 6<br>4 : f <sub>0</sub> / 4                  7 : f <sub>0</sub> x 7<br>5 : f <sub>0</sub> x 5                  8 : f <sub>0</sub> / 8 & f <sub>0</sub> x 8 | f          | Device Orientation :<br>R = Embossed Tape<br>(Standard Feed)<br>L = Embossed Tape<br>(Reverse Feed) |

## Packaging Information

### SOT-26



## Marking



SOT-26  
(TOP VIEW)

① Represents the Series name

| MARK |
|------|
| 7    |

② Represents the Output

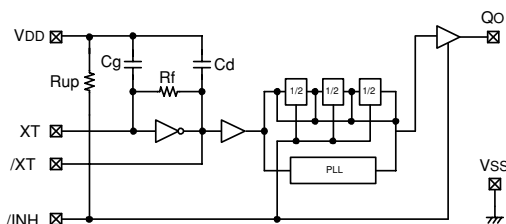
| SYMBOL | OUTPUT     |
|--------|------------|
| M      | Multiplier |
| D      | Divider    |

③ Represents the Multiplier and/or Divider Ratio

| SYMBOL | M/D               | SYMBOL | M/D                                    |
|--------|-------------------|--------|--|
| 2      | f <sub>0</sub> /2 | 6      | f <sub>0</sub> x 6                     |
| 4      | f <sub>0</sub> /4 | 7      | f <sub>0</sub> x 7                     |
| 5      | f <sub>0</sub> /5 | 8      | f <sub>0</sub> /8 & f <sub>0</sub> x 8 |

④ Represents the Assembly Lot No.  
(based on internal standards)

## Block Diagram



## Absolute Maximum Ratings

| PARAMETER               | SYMBOL | CONDITIONS      | UNITS |
|-------------------------|--------|-----------------|-------|
| Supply Voltage          | VDD    | VSS-0.3~VSS+7.0 | V     |
| Input Voltage           | VIN    | VSS-0.3~VDD+0.3 | V     |
| Power Dissipation       | Pd     | 250 (*3)        | mW    |
| Operating Ambient Temp. | Topr   | -40~+85         | °C    |
| Storage Temp.           | Tstg   | -55~+125        | °C    |

\* When measured on a glass epoxy PCB

## Electrical Characteristics

3.3V, f<sub>0</sub> x 8 multiplier (note 1)

T<sub>a</sub>=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN  | TYP | MAX  | UNITS |
|--|------------------|---|------|-----|------|-------|
| Operating Voltage                        | VDD              |   | 2.97 | 3.3 | 3.63 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4  |     |      | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |      |     | 0.4  | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OH</sub> =-8mA | 2.47 |     |      | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OL</sub> =8mA  |      |     | 0.4  | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=80MHz          |      | 10  |      | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=80MHz             |      | 1   |      | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 1.0  | 2.0 | 4.0  | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 35   | 70  | 140  | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |      | 13  |      | pF    |
|  | C <sub>d</sub>   | (note 3)  |      | 13  |      | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 0.3  | 1.0 | 2.0  | MΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |      |     | 10   | μA    |

5.0V, f<sub>0</sub> x 8 multiplier (note 2)

T<sub>a</sub>=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN | TYP | MAX | UNITS |
|--|------------------|---|-----|-----|-----|-------|
| Operating Voltage                        | VDD              |   | 4.5 | 5.0 | 5.5 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4 |     |     | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |     |     | 0.4 | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OH</sub> =-16mA | 3.9 | 4.2 |     | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OL</sub> =16mA  |     | 0.3 | 0.4 | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=160MHz         |     | 35  |     | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=160MHz            |     | 5   |     | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 0.5 | 1.0 | 2.0 | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 25  | 50  | 100 | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |     | 13  |     | pF    |
|  | C <sub>d</sub>   | (note 3)  |     | 13  |     | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 100 | 240 | 400 | kΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |     |     | 10  | μA    |

note 1 : The output frequency range is 80 MHz to 100MHz with a multiplier of f<sub>0</sub> x 8 at 3.3V

note 2 : The output frequency range is 80 MHz to 160MHz with a multiplier of f<sub>0</sub> x 8 at 5.0V

note 3 : measured value

## 3.3V, f<sub>0</sub> x 7 multiplier (note 1)

T<sub>a</sub>=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN  | TYP | MAX  | UNITS |
|--|------------------|---|------|-----|------|-------|
| Operating Voltage                        | V <sub>DD</sub>  |   | 2.97 | 3.3 | 3.63 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4  |     |      | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |      |     | 0.4  | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OH</sub> =-8mA | 2.47 |     |      | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OL</sub> =8mA  |      |     | 0.4  | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=70MHz          |      | 9   |      | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=70MHz             |      | 1   |      | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 1.0  | 2.0 | 4.0  | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 35   | 70  | 140  | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |      | 13  |      | pF    |
|  | C <sub>d</sub>   | (note 3)  |      | 13  |      | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 0.3  | 1.0 | 2.0  | MΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |      |     | 10   | μA    |

## 5.0V, f<sub>0</sub> x 7 multiplier (note 2)

T<sub>a</sub>=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN | TYP | MAX | UNITS |
|--|------------------|---|-----|-----|-----|-------|
| Operating Voltage                        | V <sub>DD</sub>  |   | 4.5 | 5.0 | 5.5 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4 |     |     | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |     |     | 0.4 | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OH</sub> =-16mA | 3.9 | 4.2 |     | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OL</sub> =16mA  |     | 0.3 | 0.4 | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=140MHz         |     | 28  |     | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=140MHz            |     | 5   |     | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 0.5 | 1.0 | 2.0 | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 25  | 50  | 100 | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |     | 13  |     | pF    |
|  | C <sub>d</sub>   | (note 3)  |     | 13  |     | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 100 | 240 | 400 | kΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |     |     | 10  | μA    |

note 1 : The output frequency range is 70 MHz to 100MHz with a multiplier of f<sub>0</sub> x 7 at 3.3V

note 2 : The output frequency range is 80 MHz to 160MHz with a multiplier of f<sub>0</sub> x 7 at 5.0V

note 3 : measured value

**3.3V, f<sub>0</sub> x 6 multiplier (note 1)**

Ta=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN  | TYP | MAX  | UNITS |
|--|------------------|---|------|-----|------|-------|
| Operating Voltage                        | V <sub>DD</sub>  |   | 2.97 | 3.3 | 3.63 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4  |     |      | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |      |     | 0.4  | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OH</sub> =-8mA | 2.47 |     |      | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OL</sub> =8mA  |      |     | 0.4  | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=60MHz          |      | 8   |      | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=60MHz             |      | 1   |      | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 1.0  | 2.0 | 4.0  | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 35   | 70  | 140  | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |      | 13  |      | pF    |
|  | C <sub>d</sub>   | (note 3)  |      | 13  |      | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 0.3  | 1.0 | 2.0  | MΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |      |     | 10   | μA    |

**5.0V, f<sub>0</sub> x 6 multiplier (note 2)**

Ta=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN | TYP | MAX | UNITS |
|--|------------------|---|-----|-----|-----|-------|
| Operating Voltage                        | V <sub>DD</sub>  |   | 4.5 | 5.0 | 5.5 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4 |     |     | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |     |     | 0.4 | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OH</sub> =-16mA | 3.9 | 4.2 |     | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OL</sub> =16mA  |     | 0.3 | 0.4 | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=120MHz         |     | 23  |     | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=120MHz            |     | 5   |     | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 0.5 | 1.0 | 2.0 | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 25  | 50  | 100 | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |     | 13  |     | pF    |
|  | C <sub>d</sub>   | (note 3)  |     | 13  |     | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 100 | 240 | 400 | kΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |     |     | 10  | μA    |

 note 1 : The output frequency range is 60 MHz to 100MHz with a multiplier of f<sub>0</sub> x 6 at 3.3V

 note 2 : The output frequency range is 80 MHz to 150MHz with a multiplier of f<sub>0</sub> x 6 at 5.0V

note 3 : measured value

## 3.3V, f<sub>0</sub> x 5 multiplier (note 1)

T<sub>a</sub>=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN  | TYP | MAX  | UNITS |
|--|------------------|---|------|-----|------|-------|
| Operating Voltage                        | V <sub>DD</sub>  |   | 2.97 | 3.3 | 3.63 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4  |     |      | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |      |     | 0.4  | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OH</sub> =-8mA | 2.47 |     |      | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =2.97V, I <sub>OL</sub> =8mA  |      |     | 0.4  | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=50MHz          |      | 7   |      | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=50MHz             |      | 1   |      | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 1.0  | 2.0 | 4.0  | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 35   | 70  | 140  | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |      | 13  |      | pF    |
|  | C <sub>d</sub>   | (note 3)  |      | 13  |      | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 0.3  | 1.0 | 2.0  | MΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |      |     | 10   | μA    |

## 5.0V, f<sub>0</sub> x 5 multiplier (note 2)

T<sub>a</sub>=25°C

| PARAMETER                                | SYMBOL           | CONDITIONS  | MIN | TYP | MAX | UNITS |
|--|------------------|---|-----|-----|-----|-------|
| Operating Voltage                        | V <sub>DD</sub>  |   | 4.5 | 5.0 | 5.5 | V     |
| 'H' Level Input Voltage                  | V <sub>IH</sub>  |   | 2.4 |     |     | V     |
| 'L' Level Input Voltage                  | V <sub>IL</sub>  |   |     |     | 0.4 | V     |
| 'H' Level Output Voltage                 | V <sub>OH</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OH</sub> =-16mA | 3.9 | 4.2 |     | V     |
| 'L' Level Output Voltage                 | V <sub>OL</sub>  | CMOS: V <sub>DD</sub> =4.5V, I <sub>OL</sub> =16mA  |     | 0.3 | 0.4 | V     |
| Consumption Current 1                    | I <sub>DD1</sub> | /INH="OPEN", C <sub>L</sub> =15pF, f=100MHz         |     | 23  |     | mA    |
| Consumption Current 2                    | I <sub>DD2</sub> | /INH="L", C <sub>L</sub> =15pF, f=100MHz            |     | 5   |     | mA    |
| Input pull up resistance 1               | R <sub>up1</sub> | /INH="L"  | 0.5 | 1.0 | 2.0 | MΩ    |
| Input pull up resistance 2               | R <sub>up2</sub> | /INH=0.7V <sub>DD</sub>                             | 25  | 50  | 100 | kΩ    |
| Internal Oscillation Capacitance         | C <sub>g</sub>   | (note 3)  |     | 13  |     | pF    |
|  | C <sub>d</sub>   | (note 3)  |     | 13  |     | pF    |
| Internal Oscillation Feedback Resistance | R <sub>f</sub>   |   | 100 | 240 | 400 | kΩ    |
| Output Off Leak Current                  | I <sub>oz</sub>  | /INH="L"  |     |     | 10  | μA    |

note 1 : The output frequency range is 50 MHz to 100MHz with a multiplier of f<sub>0</sub> x 5 at 3.3V

note 2 : The output frequency range is 80 MHz to 125MHz with a multiplier of f<sub>0</sub> x 5 at 5.0V

note 3 : measured value

## ■ Switching Characteristics

3.3V

Ta=25°C

| PARAMETER                     | SYMBOL | CONDITIONS                        | MIN | TYP | MAX | UNITS |
|-------------------------------|--------|-----------------------------------|-----|-----|-----|-------|
| Output Rise Time              | tr     | CL=15pF, 0.1VDD ~ 0.9VDD (note 1) |     | 2.0 |     | ns    |
| Output Fall Time              | tf     | CL=15pF, 0.9VDD ~ 0.1VDD (note 1) |     | 2.0 |     | ns    |
| Output DUTY Cycle             | DUTY   | CMOS: 0.5VDD, CL=15pF             | 45  |     | 55  | %     |
| Output Disenable (Delay Time) | tplz   | CL=15pF (note 1)                  |     |     | 100 | ns    |
| Output Enable (Delay Time)    | tpzl   | CL=15pF (note 1)                  |     |     | 100 | ns    |
| Jitter                        | tj     | 1 $\sigma$ (note 1)               |     | 50  |     | ps    |

5.0V

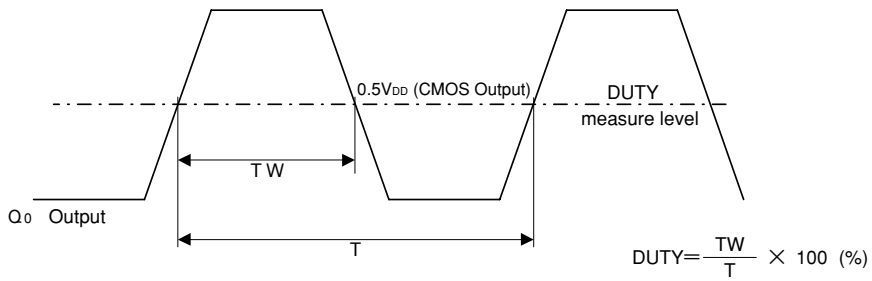
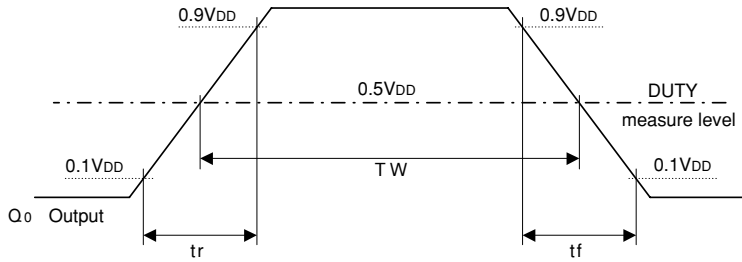
Ta=25°C

| PARAMETER                     | SYMBOL | CONDITIONS                        | MIN | TYP | MAX | UNITS |
|-------------------------------|--------|-----------------------------------|-----|-----|-----|-------|
| Output Rise Time              | tr     | CL=15pF, 0.1VDD ~ 0.9VDD (note 1) |     | 1.5 |     | ns    |
| Output Fall Time              | tf     | CL=15pF, 0.9VDD ~ 0.1VDD (note 1) |     | 1.5 |     | ns    |
| Output DUTY Cycle             | DUTY   | CMOS: 0.5VDD, CL=15pF             | 45  |     | 55  | %     |
| Output Disenable (Delay Time) | tplz   | CL=15pF (note 1)                  |     |     | 100 | ns    |
| Output Enable (Delay Time)    | tpzl   | CL=15pF (note 1)                  |     |     | 100 | ns    |
| Jitter                        | tj     | 1 $\sigma$ (note 1)               |     | 50  |     | ps    |

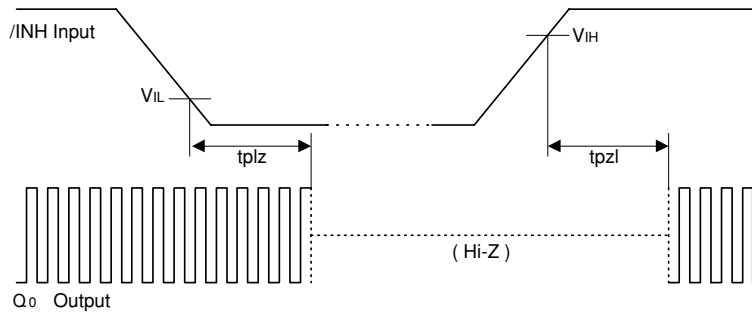
note 1 : measured value

## Switching Characteristics

1) CMOS Level : tr, tf, Duty



2) Output Disable/Enable Delay Time



\*)  $/INH$  pin input waveform :  $t_r = t_f =$  less than 10 ns